DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1996 Apr 26 1999 May 11



Product data sheet

Voltage regulator diodes

BZV85 series

FEATURES

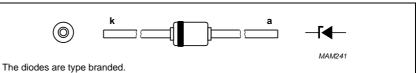
- Total power dissipation: max. 1.3 W
- Tolerance series: approx. ±5%
- Working voltage range: nom. 3.6 to 75 V (E24 range)
- Non-repetitive peak reverse power dissipation: max. 60 W.

APPLICATIONS

• Stabilization purposes.

DESCRIPTION

Medium-power voltage regulator diodes in hermetically sealed leaded glass SOD66 (DO-41) packages. The diodes are available in the normalized E24 approx. $\pm 5\%$ tolerance range. The series consists of 33 types with nominal working voltages from 3.6 to 75 V (BZV85-C3V6 to BZV85-C75).



31

Fig.1 Simplified outline (SOD66; DO-41) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _F	continuous forward current		_	500	mA
I _{ZSM}	non-repetitive peak reverse current	$t_p = 100 \ \mu s$; square wave; $T_j = 25 \ ^\circ C$ prior to surge; see Fig.3	see Table "Per type		
		$t_p = 10$ ms; half sinewave; $T_j = 25$ °C prior to surge	see Table "Per type		
P _{tot}	total power dissipation	T _{amb} = 25 °C; lead length 10 mm; note 1	-	1	W
		note 2	-	1.3	W
P _{ZSM}	non-repetitive peak reverse power dissipation	t _p = 100 μs; square wave; T _j = 25 °C prior to surge	_	60	W
T _{stg}	storage temperature		-65	+200	°C
Tj	junction temperature		-	200	°C

Notes

- 1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.
- 2. If the leads are kept at T_{tp} = 55 °C at 4 mm from body.

ELECTRICAL CHARACTERISTICS

Total series

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA; see Fig.4	1	V

NXP Semiconductors

BZV85 series

BZV85-	VOL Vz	KING FAGE (V) ^{Ztest}	RESISTANCE S r _{dif} (Ω)		- 、 /		$\begin{array}{ll} TEST & DIODE CAP. \\ CURRENT & C_d (pF) \\ I_{Ztest} (mA) & at f = 1 MHz; \\ & V_R = 0 \ V \end{array}$		SE Tat SE SE	NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM}		
CXXX								I _R (μΑ)	V _R (V)	at t _p = 100 μs; T _{amb} = 25 °C	at t _p = 10 ms; T _{amb} = 25 °C	
	MIN.	MAX.	MAX.	MIN.	MAX.		MAX.	MAX.	(•)	MAX. (A)	MAX. (mA)	
3V6	3.4	3.8	15	-3.5	-1.0	60	450	50	1.0	8.0	2000	
3V9	3.7	4.1	15	-3.5	-1.0	60	450	10	1.0	8.0	1950	
4V3	4.0	4.6	13	-2.7	0	50	450	5	1.0	8.0	1850	
4V7	4.4	5.0	13	-2.0	+0.7	45	300	3	1.0	8.0	1800	
5V1	4.8	5.4	10	-0.5	+2.2	45	300	3	2.0	8.0	1750	
5V6	5.2	6.0	7	0	2.7	45	300	2	2.0	8.0	1700	
6V2	5.8	6.6	4	0.6	3.6	35	200	2	3.0	7.0	1620	
6V8	6.4	7.2	3.5	1.3	4.3	35	200	2	4.0	7.0	1550	
7V5	7.0	7.9	3	2.5	5.5	35	150	1	4.5	5.0	1500	
8V2	7.7	8.7	5	3.1	6.1	25	150	0.7	5.0	5.0	1 400	
9V1	8.5	9.6	5	3.8	7.2	25	150	0.7	6.5	4.0	1340	
10	9.4	10.6	8	4.7	8.5	25	90	0.2	7.0	4.0	1200	
11	10.4	11.6	10	5.3	9.3	20	85	0.2	7.7	3.0	1100	
12	11.4	12.7	10	6.3	10.8	20	85	0.2	8.4	3.0	1000	
13	12.4	14.1	10	7.4	12.0	20	80	0.2	9.1	3.0	900	
15	13.8	15.6	15	8.9	13.6	15	75	0.05	10.5	2.5	760	
16	15.3	17.1	15	10.7	15.4	15	75	0.05	11.0	1.75	700	
18	16.8	19.1	20	11.8	17.1	15	70	0.05	12.5	1.75	600	
20	18.8	21.2	24	13.6	19.1	10	60	0.05	14.0	1.75	540	
22	20.8	23.3	25	16.6	22.1	10	60	0.05	15.5	1.5	500	
24	22.8	25.6	30	18.3	24.3	10	55	0.05	17	1.5	450	
27	25.1	28.9	40	20.1	27.5	8	50	0.05	19	1.2	400	
30	28.0	32.0	45	22.4	32.0	8	50	0.05	21	1.2	380	

Per type $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

1999 May 11

ω

Product data sheet

1999	
May	
7	

BZV85-	LICOL		RESISTANCE r _{dif} (Ω)		$\begin{array}{c} \text{RESISTANCE} & \text{S}_{\text{Z}} \left(\text{mV/K}\right) \\ \text{r}_{\text{dif}} \left(\Omega\right) & \text{at } \text{I}_{\text{Ztest}} \end{array}$		$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM}	
CXXX								I _R (μΑ)	V _R	at t _p = 100 μs; T _{amb} = 25 °C	at t _p = 10 ms; T _{amb} = 25 °C	
	MIN. MAX.	MAX.	MIN.	MAX.		MAX.	MAX.	(V)	MAX. (A)	MAX. (mA)		
33	31.0	35.0	45	24.8	35.0	8	45	0.05	23	1.0	350	
36	34.0	38.0	50	27.2	39.9	8	45	0.05	25	0.9	320	
39	37.0	41.0	60	29.6	43.0	6	45	0.05	27	0.8	296	
43	40.0	46.0	75	34.0	48.3	6	40	0.05	30	0.7	270	
47	44.0	50.0	100	37.4	52.5	4	40	0.05	33	0.6	246	
51	48.0	54.0	125	40.8	56.5	4	40	0.05	36	0.5	226	
56	52.0	60.0	150	46.8	63.0	4	40	0.05	39	0.4	208	
62	58.0	66.0	175	52.2	72.5	4	35	0.05	43	0.4	186	
68	64.0	72.0	200	60.5	81.0	4	35	0.05	48	0.35	171	
75	70.0	80.0	225	66.5	88.0	4	35	0.05	53	0.3	161	

BZV85 series

Voltage regulator diodes

BZV85 series

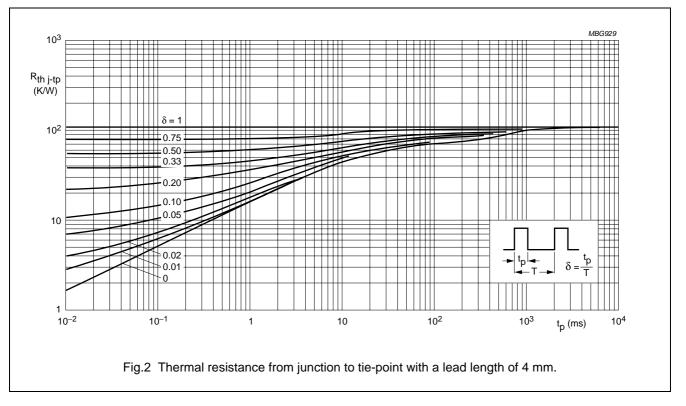
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length 4 mm; see Fig.2	110	K/W
R _{th j-a}	thermal resistance from junction to ambient	lead length10 mm; note 1	175	K/W

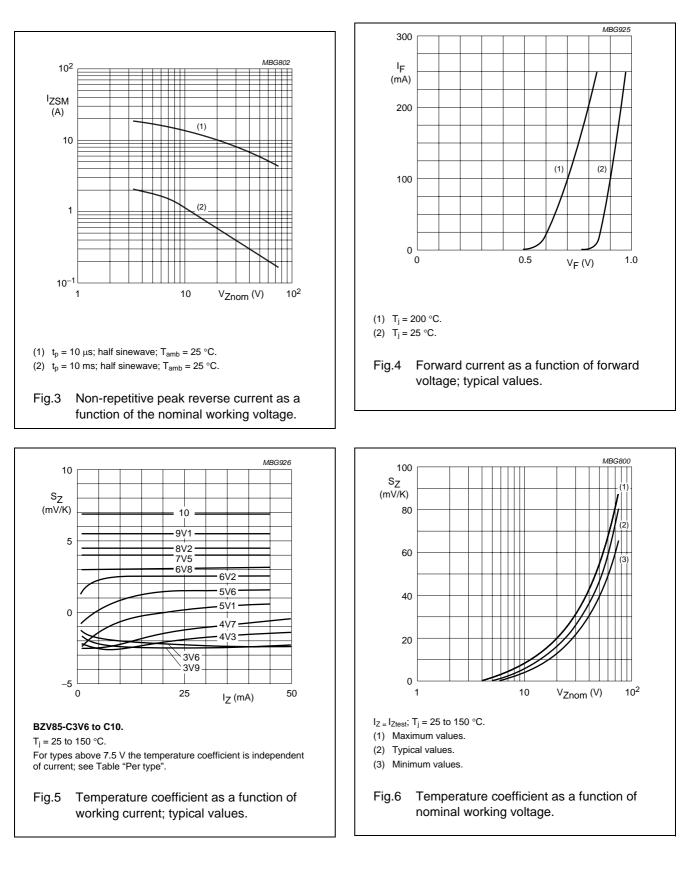
Note

1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.

GRAPHICAL DATA



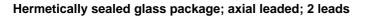
BZV85 series

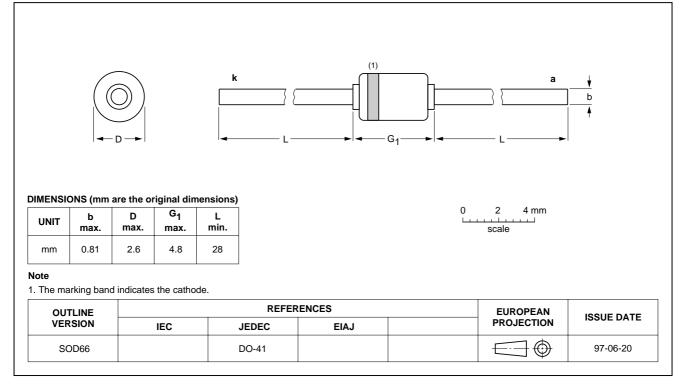


SOD66

Voltage regulator diodes

PACKAGE OUTLINE





BZV85 series

BZV85 series

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

DISCLAIMERS

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions

above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

© NXP B.V. 2009

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

115002/00/02/pp9

Date of release: 1999 May 11

Document order number: 9397 750 05929

